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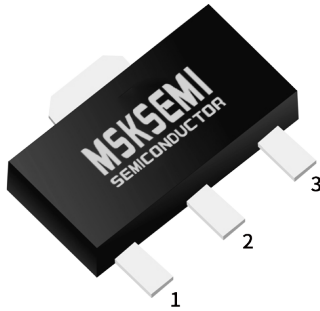


GDT



PLED

Product data sheet



SOT-89

Package	Pin assignment		
	1	2	3
All	T1	T2	G

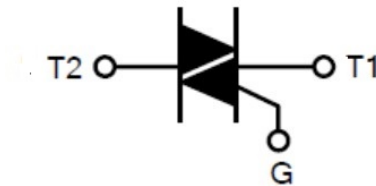
## FEATURES

This device of sensitive TRIAC product is a glass passivated device, has a low gate trigger current, high stability in gate trigger current to variation of operating temperature and high off state voltage.

## APPLICATIONS

This device is suitable for low power AC switching application, phase control application such as fan speed and temperature modulation control, lighting control and static switching relay.

## SYMBOL:



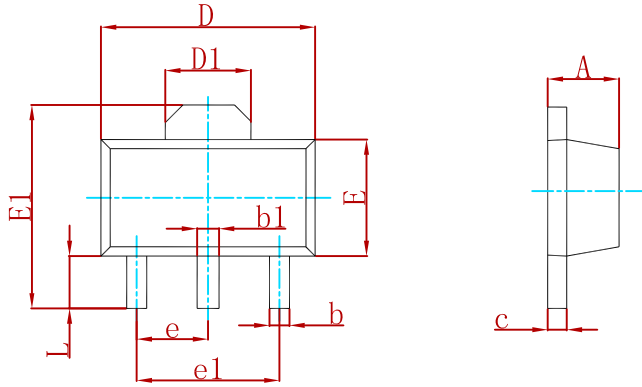
## ABSOLUTE MAXIMUM RATINGS (T<sub>J</sub>=25°C)

PARAMETER	SYMBOL	VALUE	UNIT	
Repetitive Peak Off-State Voltages	V <sub>DRM</sub> , V <sub>RRM</sub>	600	V	
RMS on-State Current	I <sub>T(RMS)</sub>	2	A	
Non-Repetitive Peak On-State Current	I <sub>TSM</sub>	20	A	
I <sup>2</sup> t for fusing	I <sup>2</sup> t	2.6	A <sup>2</sup> s	
Repetitive rate of rise of on-state current after triggering	dI <sub>T</sub> /dt	I	50	A/μs
		II	50	
		III	50	
		IV	10	
Peak gate current	I <sub>GM</sub>	1.8	A	
Peak Gate Power	P <sub>GM</sub>	4	W	
Average Gate Power	P <sub>G(AV)</sub>	0.5	W	
Operating junction temperature	T <sub>J</sub>	+125	°C	
Storage Temperature	T <sub>STG</sub>	-40 ~ +150	°C	

**ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C)**

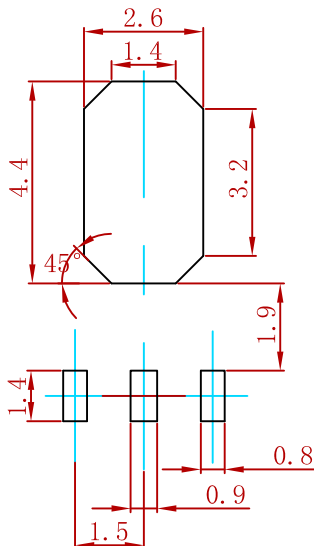
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
Peak Repetitive Forward or Reverse Blocking Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>AK</sub> = Rated V <sub>DRM</sub> or V <sub>RRM</sub> ;		10	uA
Gate Trigger Current	I <sub>GT</sub>	V <sub>D</sub> =12V, R <sub>L</sub> =100Ω	I	10	mA
			II	10	
			III	10	
			IV	25	
Gate Trigger Voltage	V <sub>GT</sub>	V <sub>D</sub> =12V, I <sub>T</sub> =100mA		1.5	V
Peak Forward On-State Voltage	V <sub>TM</sub>	I <sub>T</sub> =4.0A,		1.7	V
Latch Current	I <sub>L</sub>	V <sub>D</sub> =12V I <sub>G</sub> =0.1A,	I	15	mA
			II	15	
			III	15	
			IV	20	
Holding Current	I <sub>H</sub>	V <sub>D</sub> =12V ,I <sub>G</sub> =0.1A		15	mA
Gate Non-Trigger Voltage	V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub>	0.2		V
Critical Rate of Rise of Off-State Voltage	dV/dt	V <sub>D</sub> =67%V <sub>DRM</sub> , R <sub>GK</sub> =1kΩ,	20		V/μs

**PACKAGE MECHANICAL DATA**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047

**Suggested Pad Layout**



Note:  
 1. Controlling dimension: in millimeters.  
 2. General tolerance:  $\pm 0.05\text{mm}$ .  
 3. The pad layout is for reference purposes only.

**REEL SPECIFICATION**

P/N	PKG	QTY
BT134-600-MS	SOT-89	1000

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